

Isc N-Channel MOSFET Transistor
IRFSL23N20D
• FEATURES

- With TO-262 packaging
- High speed switching
- Low gate input resistance
- Standard level gate drive
- Easy to use
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

• APPLICATIONS

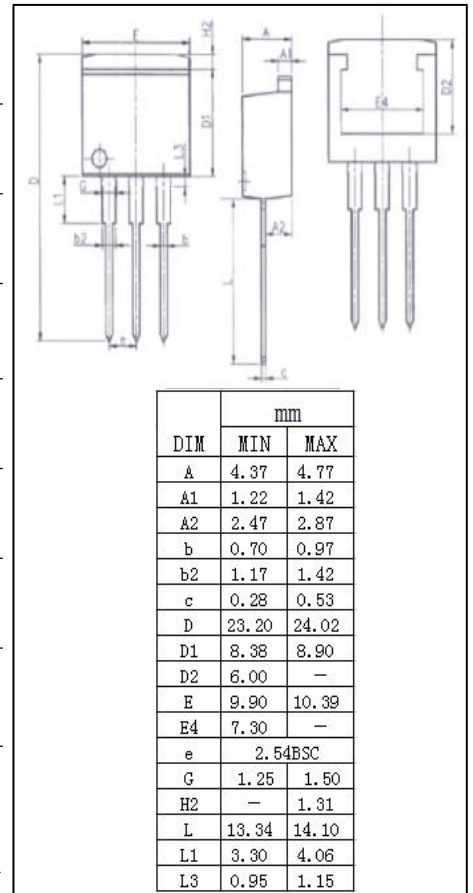
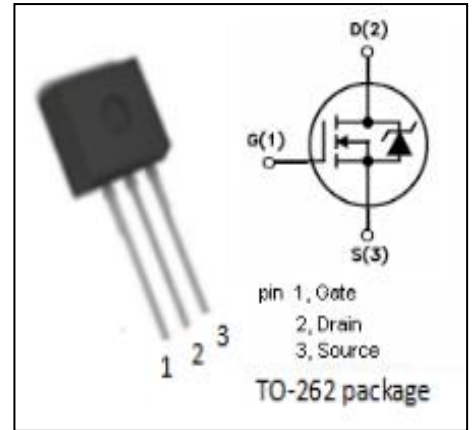
- Power supply
- Switching applications

• ABSOLUTE MAXIMUM RATINGS($T_a=25^{\circ}\text{C}$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DS}	Drain-Source Voltage	200	V
V_{GS}	Gate-Source Voltage	± 30	V
I_D	Drain Current-Continuous	24	A
P_D	Total Dissipation @ $T_c=25^{\circ}\text{C}$	3.8	W
T_j	Max. Operating Junction Temperature	-55~175	$^{\circ}\text{C}$
T_{stg}	Storage Temperature	-55~175	$^{\circ}\text{C}$

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th(j-c)}$	Channel-to-case thermal resistance	0.9	$^{\circ}\text{C/W}$



Isc N-Channel MOSFET Transistor**IRFSL23N20D****ELECTRICAL CHARACTERISTICS** $T_C=25^{\circ}\text{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV_{DSS}	Drain-Source Breakdown Voltage	$V_{GS}=0V; I_D=1\text{mA}$	200			V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}; I_D=250\ \mu\text{A}$	3		5.5	V
$R_{DS(on)}$	Drain-Source On-Resistance	$V_{GS}=10V; I_D=14\text{A}$			100	$\text{m}\Omega$
I_{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm 30V; V_{DS}=0V$			± 100	nA
I_{DSS}	Drain-Source Leakage Current	$V_{DS}=200V; V_{GS}=0V$			25	μA
V_{SD}	Diode forward voltage	$I_S=14\text{A}, V_{GS}=0V$			1.3	V

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